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<u>Vishay Semiconductor/Diodes Division</u> <u>VFT1080S-M3/4W</u>

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Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite

Datasheet of VFT1080S-M3/4W - DIODE SCHOTTKY 10A 80V ITO-220AB Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



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VFT1080S

COMPLIANT

FREE

Vishay General Semiconductor

Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.52 \text{ V}$ at $I_F = 5 \text{ A}$

TMBS® ITO-220AB



| PRIMARY CHARACTERISTICS | | | |
|---|------------|--|--|
| I _{F(AV)} | 10 A | | |
| V _{RRM} | 80 V | | |
| I _{FSM} | 100 A | | |
| V _F at I _F = 10 A | 0.60 V | | |
| T _J max. | 150 °C | | |
| Package | ITO-220AB | | |
| Diode variation | Single die | | |

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation
- Solder bath temperature 275 °C max. 10 s, per JESD 22-B106
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: ITO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted) | | | | |
|--|-----------------------------------|---------------|------|--|
| PARAMETER | SYMBOL | VFT1080S | UNIT | |
| Maximum repetitive peak reverse voltage | V_{RRM} | 80 | V | |
| Maximum average forward rectified current (fig. 1) | I _{F(AV)} | 10 | Α | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load | I _{FSM} | 100 | А | |
| Voltage rate of change (rated V _R) | dV/dt | 10 000 | V/µs | |
| Isolation voltage from termal to heatsink t = 1 min | V _{AC} | 1500 | V | |
| Operating junction and storage temperature range | T _J , T _{STG} | - 55 to + 150 | °C | |

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| ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | | |
|---|--|-------------------------|-------------------------------|------|------|------|--|
| PARAMETER | TEST CONDITIONS | | SYMBOL | TYP. | MAX. | UNIT | |
| Instantaneous forward voltage | I _F = 5 A | T _A = 25 °C | V _F ⁽¹⁾ | 0.57 | - | V | |
| | I _F = 10 A | | | 0.67 | 0.81 | | |
| | I _F = 5 A | T _A = 125 °C | | 0.52 | - | | |
| | I _F = 10 A | | | 0.60 | 0.70 | | |
| Reverse current | $V_R = 80 \text{ V}$ $T_A = 20 \text{ T}_A = 10 $ | T _A = 25 °C | I _R ⁽²⁾ | 20 | 600 | μΑ | |
| | | T _A = 125 °C | | 10 | 20 | mA | |

Notes

 $^{(1)}$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

| THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | |
|---|----------------|----------|------|--|
| PARAMETER | SYMBOL | VFT1080S | UNIT | |
| Typical thermal resistance | $R_{	heta JC}$ | 5.5 | °C/W | |

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|----------------|-----------------|--------------|---------------|---------------|--|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | | |
| ITO-220AB | VFT1080S-M3/4W | 1.73 | 4W | 50/tube | Tube | | |

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

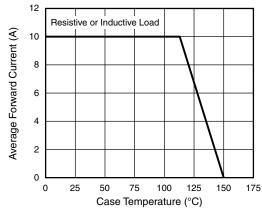


Fig. 1 - Maximum Forward Current Derating Curve

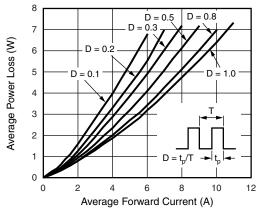
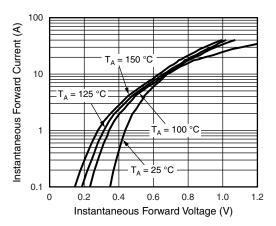


Fig. 2 - Forward Power Dissipation Characteristics

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Fig. 3 - Typical Instantaneous Forward Characteristics

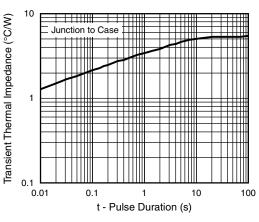


Fig. 5 - Typical Transient Thermal Impedance

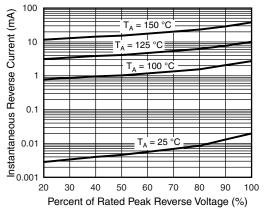


Fig. 4 - Typical Reverse Characteristics

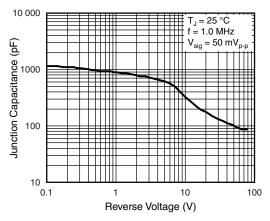
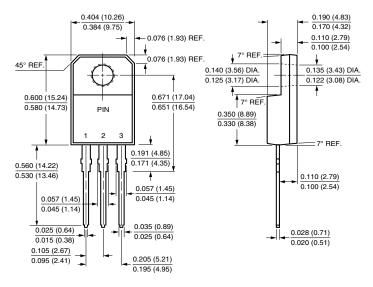


Fig. 6 - Typical Junction Capacitance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

ITO-220AB



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